

Phase Control Thyristors (Hockey PUK Version), 500 A


A-PUK (TO-200AB)

RoHS
COMPLIANT

FEATURES

- Center amplifying gate
- Metal case with ceramic insulator
- International standard case A-PUK (TO-200AB)
- Extended temperature range
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

- DC motor controls
- Controlled DC power supplies
- AC controllers

PRIMARY CHARACTERISTICS	
$I_{T(AV)}$	500 A
V_{DRM}/V_{RRM}	400 V, 600 V
V_{TM}	1.35 V
I_{GT}	90 mA
T_J	-40 °C to +150 °C
Package	A-PUK (TO-200AB)
Circuit configuration	Single SCR

MAJOR RATINGS AND CHARACTERISTICS			
PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{T(AV)}$		500	A
	T_{hs}	80	°C
$I_{T(RMS)}$		1130	A
	T_{hs}	25	°C
I_{TSM}	50 Hz	7200	A
	60 Hz	7500	
I^2t	50 Hz	260	kA^2s
	60 Hz	230	
V_{DRM}/V_{RRM}		400 to 600	V
t_q	Typical	100	μs
T_J		-40 to 150	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER	VOLTAGE CODE	V_{DRM}/V_{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I_{DRM}/I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA
VS-ST280CH..C	04	400	500	75
	06	600	700	

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS	
Maximum average on-state current at heatsink temperature	$I_{T(AV)}$	180° conduction, half sine wave double side (single side) cooled			500 (185)	A	
					80 (110)	°C	
Maximum RMS on-state current	$I_{T(RMS)}$	DC at 25 °C heatsink temperature double side cooled			1130	A	
Maximum peak, one-cycle non-repetitive surge current	I_{TSM}	$t = 10 \text{ ms}$	No voltage reapplied	100 % V_{RRM} reapplied	7200		
		$t = 8.3 \text{ ms}$			7500		
		$t = 10 \text{ ms}$	100 % V_{RRM} reapplied		6000		
		$t = 8.3 \text{ ms}$			6300		
Maximum I^2t for fusing	I^2t	$t = 10 \text{ ms}$	No voltage reapplied	100 % V_{RRM} reapplied	260	kA^2s	
		$t = 8.3 \text{ ms}$			235		
		$t = 10 \text{ ms}$	100 % V_{RRM} reapplied		180		
		$t = 8.3 \text{ ms}$			165		
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1 \text{ to } 10 \text{ ms}$, no voltage reapplied			2600	$\text{kA}^2\sqrt{\text{s}}$	
Low level value of threshold voltage	$V_{T(TO)1}$	$(16.7 \% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_J \text{ maximum}$			0.84	V	
High level value of threshold voltage	$V_{T(TO)2}$	$(I > \pi \times I_{T(AV)})$, $T_J = T_J \text{ maximum}$			0.88		
Low level value of on-state slope resistance	r_{t1}	$(16.7 \% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_J \text{ maximum}$			0.50	$\text{m}\Omega$	
High level value of on-state slope resistance	r_{t2}	$(I > \pi \times I_{T(AV)})$, $T_J = T_J \text{ maximum}$			0.47		
Maximum on-state voltage	V_{TM}	$I_{pk} = 1000 \text{ A}$, $T_J = T_J \text{ maximum}$, $t_p = 10 \text{ ms}$ sine pulse			1.35	V	
Maximum holding current	I_H	$T_J = 25 \text{ °C}$, anode supply 12 V resistive load			600	mA	
Maximum (typical) latching current	I_L				1000 (300)		

SWITCHING						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 Ω, $t_r \leq 1 \mu\text{s}$ $T_J = T_J \text{ maximum}$, anode voltage $\leq 80 \% V_{DRM}$			1000	$\text{A}/\mu\text{s}$
Typical delay time	t_d	Gate current 1 A, $dl_g/dt = 1 \text{ A}/\mu\text{s}$ $V_d = 0.67 \% V_{DRM}$, $T_J = 25 \text{ °C}$			1.0	μs
Typical turn-off time	t_q	$I_{TM} = 300 \text{ A}$, $T_J = T_J \text{ maximum}$, $dl/dt = 20 \text{ A}/\mu\text{s}$, $V_R = 50 \text{ V}$, $dV/dt = 20 \text{ V}/\mu\text{s}$, gate 0 V 100 Ω, $t_p = 500 \mu\text{s}$			100	

BLOCKING						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNIT S
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J \text{ maximum}$ linear to 80 % rated V_{DRM}			500	$\text{V}/\mu\text{s}$
Maximum peak reverse and off-state leakage current	I_{RRM} , I_{DRM}	$T_J = T_J \text{ maximum}$, rated V_{DRM}/V_{RRM} applied			75	mA

TRIGGERING							
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES		UNITS	
				TYP.	MAX.		
Maximum peak gate power	P_{GM}	$T_J = T_J$ maximum, $t_p \leq 5$ ms		10.0		W	
Maximum average gate power	$P_{G(AV)}$	$T_J = T_J$ maximum, $f = 50$ Hz, $d\% = 50$		2.0			
Maximum peak positive gate current	I_{GM}	$T_J = T_J$ maximum, $t_p \leq 5$ ms		3.0		A	
Maximum peak positive gate voltage	$+ V_{GM}$	$T_J = T_J$ maximum, $t_p \leq 5$ ms		20		V	
Maximum peak negative gate voltage	$- V_{GM}$			5.0			
DC gate current required to trigger	I_{GT}	$T_J = -40$ °C	Maximum required gate trigger/current/voltage are the lowest value which will trigger all units 12 V anode to cathode applied		180	-	
		$T_J = 25$ °C			90	150	
		$T_J = 150$ °C			30	-	
DC gate voltage required to trigger	V_{GT}	$T_J = -40$ °C			2.9	-	
		$T_J = 25$ °C			1.8	3.0	
		$T_J = 150$ °C			1.0	-	
DC gate current not to trigger	I_{GD}	$T_J = T_J$ maximum	Maximum gate current/voltage not to trigger is the maximum value which will not trigger any unit with rated V_{DRM} anode to cathode applied		10		mA
DC gate voltage not to trigger	V_{GD}				0.30		V

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum operating junction and storage temperature range	T_J, T_{Stg}			- 40 to 150	°C	
Maximum thermal resistance, junction to heatsink	R_{thJ-hs}	DC operation single side cooled		0.17		
		DC operation double side cooled		0.08		
Maximum thermal resistance, case to heatsink	R_{thC-hs}	DC operation single side cooled		0.033	K/W	
		DC operation double side cooled		0.017		
Mounting force, ± 10 %				4900 (500)	N (kg)	
Approximate weight				50		
Case style		See dimensions - link at the end of datasheet		A-PUK (TO-200AB)		

ΔR_{thJ-hs} CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION		RECTANGULAR CONDUCTION		TEST CONDITIONS	UNITS
	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE		
180°	0.016	0.017	0.011	0.011	$T_J = T_J$ maximum	K/W
120°	0.019	0.019	0.019	0.019		
90°	0.024	0.024	0.026	0.026		
60°	0.035	0.035	0.036	0.037		
30°	0.060	0.060	0.060	0.061		

Note

- The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC

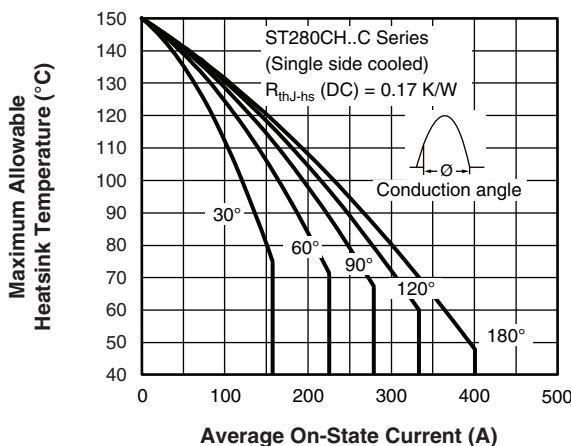


Fig. 1 - Current Ratings Characteristics

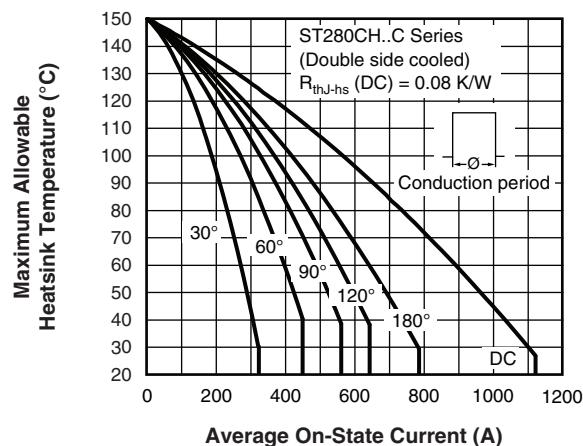


Fig. 4 - Current Ratings Characteristics

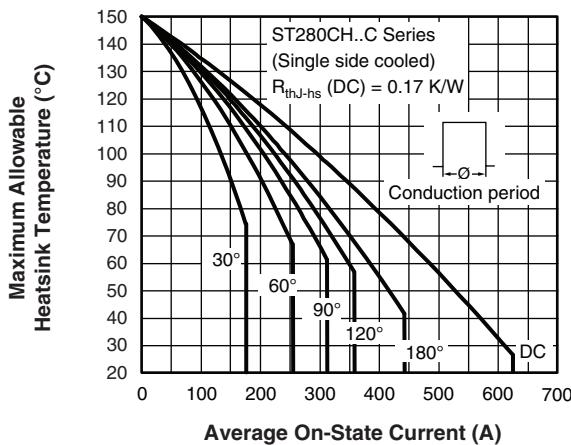


Fig. 2 - Current Ratings Characteristics

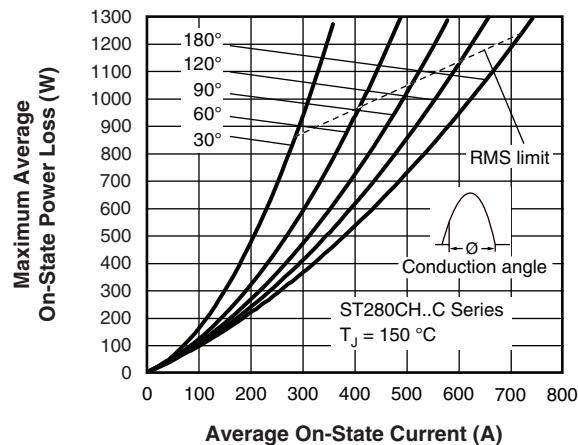


Fig. 5 - On-State Power Loss Characteristics

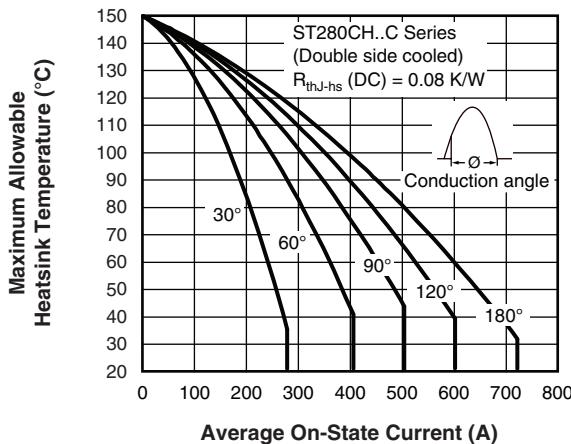


Fig. 3 - Current Ratings Characteristics

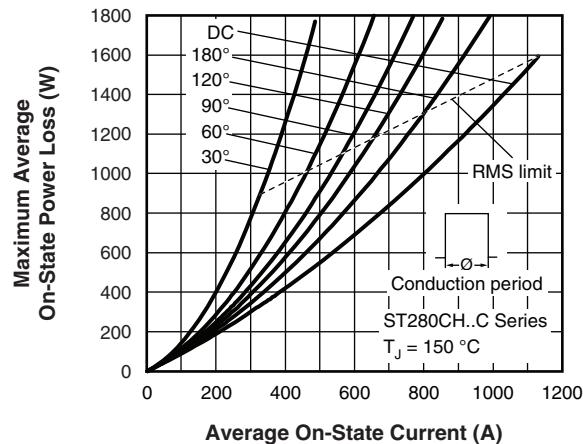


Fig. 6 - On-State Power Loss Characteristics

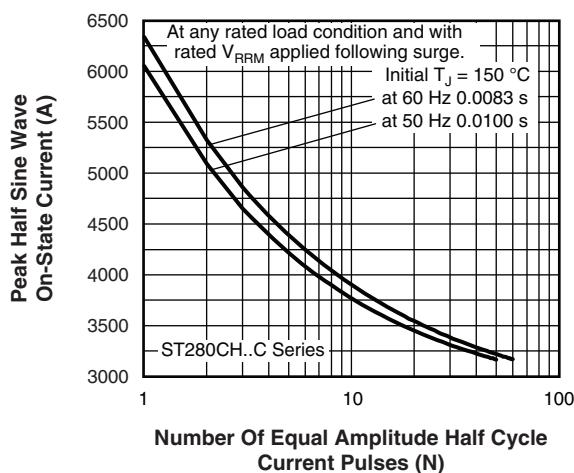


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

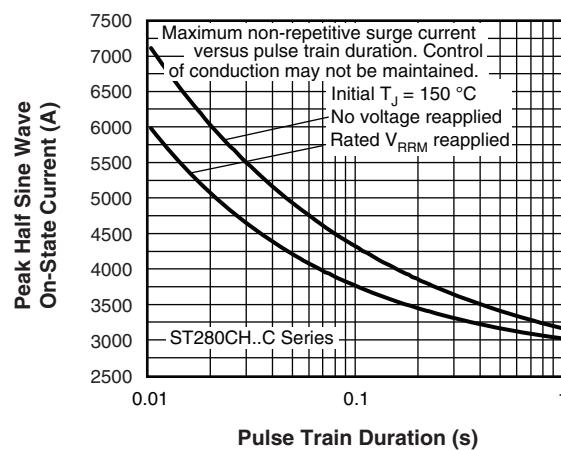


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

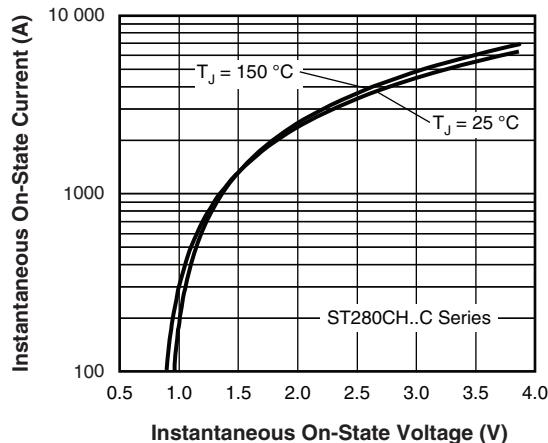


Fig. 9 - On-State Voltage Drop Characteristics

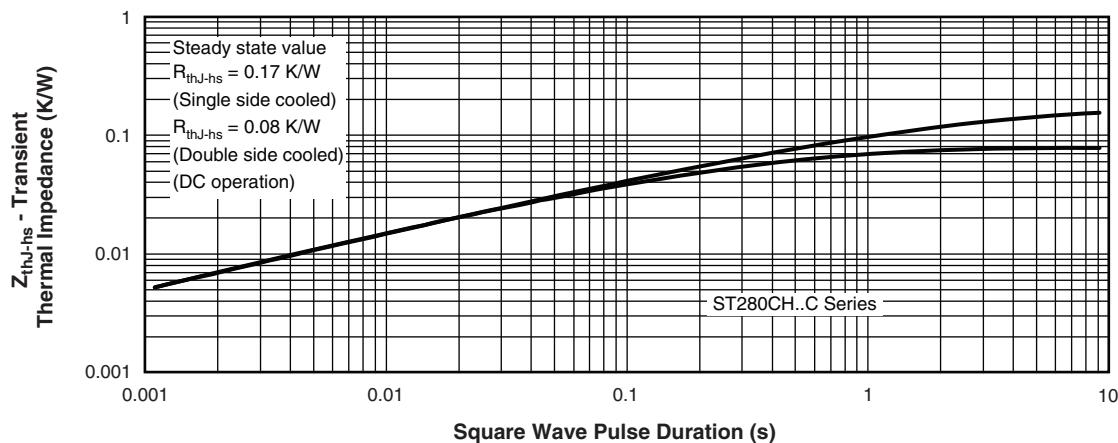


Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristics

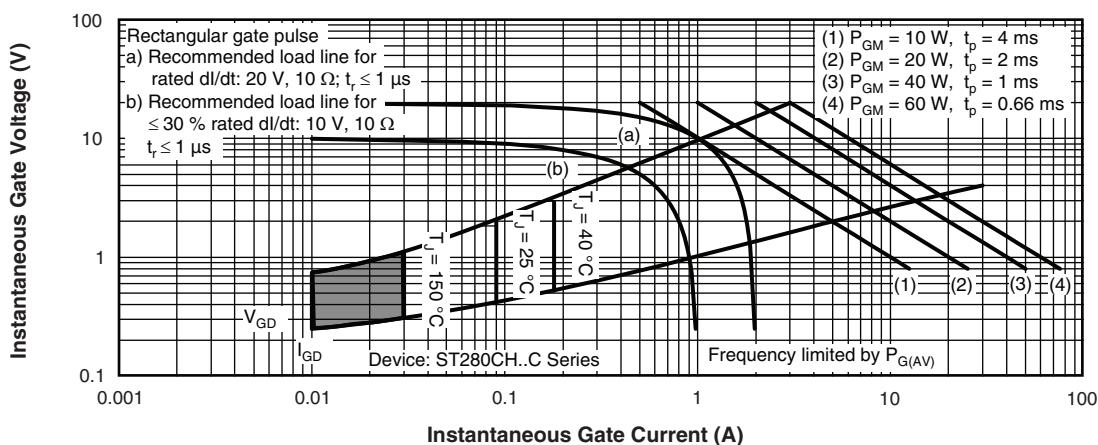


Fig. 11 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code	VS-	ST	28	0	CH	06	C	1	-
	(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)	(9)

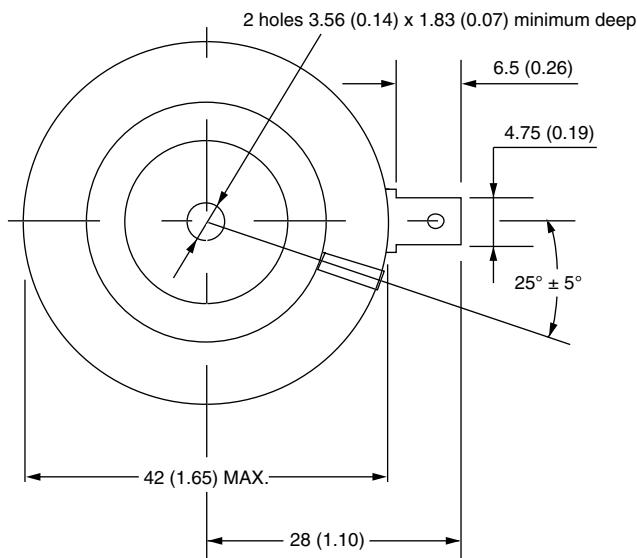
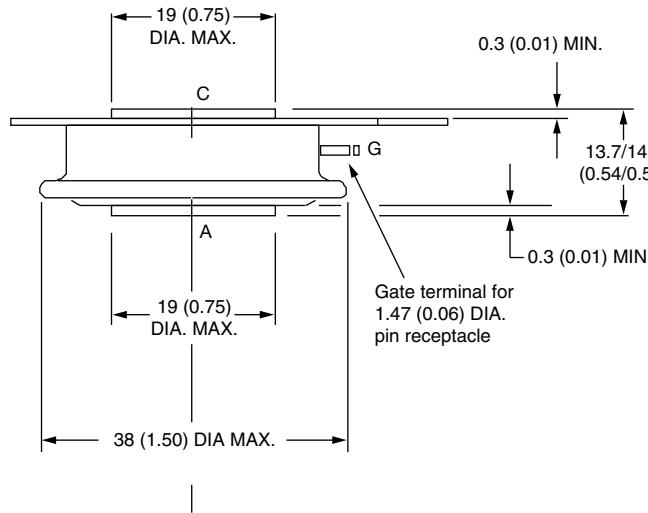
- 1** - Vishay Semiconductors product
- 2** - Thyristor
- 3** - Essential part number
- 4** - 0 = converter grade
- 5** - CH = ceramic PUK, high temperature
- 6** - Voltage code x 100 = V_{RRM} (see Voltage Ratings table)
- 7** - C = PUK case A-PUK (TO-200AB)
- 8** - 0 = eyelet terminals (gate and auxiliary cathode unsoldered leads)
 - 1 = fast-on terminals (gate and auxiliary cathode unsoldered leads)
 - 2 = eyelet terminals (gate and auxiliary cathode soldered leads)
 - 3 = fast-on terminals (gate and auxiliary cathode soldered leads)
- 9** - Critical dV/dt :
 - None = 500 V/ μs (standard selection)
 - L = 1000 V/ μs (special selection)

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95074

A-PUK (TO-200AB)

DIMENSIONS in millimeters (inches)

Anode to gate
 Creepage distance: 7.62 (0.30) minimum
 Strike distance: 7.12 (0.28) minimum



Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[Vishay](#):

[VS-ST280CH06C0](#) [VS-ST280CH06C1](#) [VS-ST280CH04C1](#) [VS-ST280CH04C0](#)